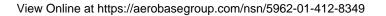
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Memory Microcircuit - Page 1 of 1





Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

55.00 nanoseconds delay

Memory Device Type:

Pal

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0